



## GaAs MMIC I/Q MIXER 3 - 7 GHz

### Typical Applications

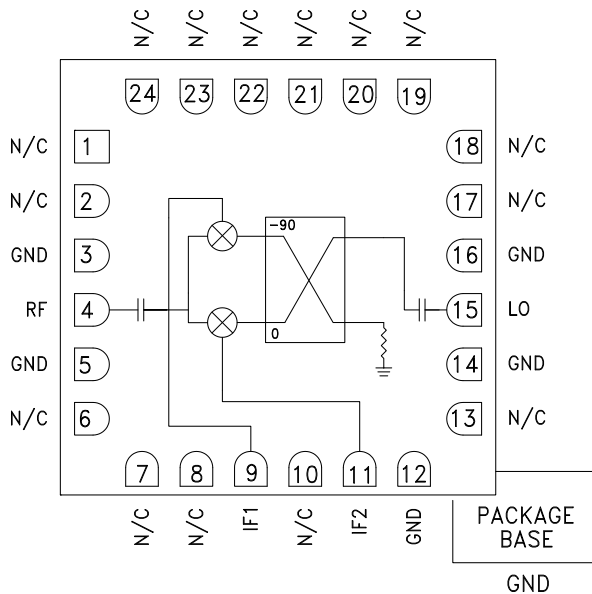
The HMC620LC4 is ideal for:

- Point-to-Point
- Point-to-Multi-Point Radio
- WiMAX & Fixed Wireless
- VSAT

### Features

- Wide IF Bandwidth: DC - 3.5 GHz
- High Image Rejection: 32 dB
- High LO to RF Isolation: 43 dB
- High Input IP3: +22 dBm
- 24 Lead Ceramic 4x4 SMT Package: 16mm<sup>2</sup>

### Functional Diagram



### General Description

The HMC620LC4 is a compact I/Q MMIC mixer in a leadless "Pb free" RoHS compliant SMT package, which can be used as either an Image Reject Mixer (IRM) or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs MESFET process. A low frequency quadrature hybrid was used to produce a 100 MHz upper side band (USB) IF output. This product is a much smaller and more consistent alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC620LC4 is compatible with high volume surface mount manufacturing techniques.

### Electrical Specifications, $T_A = +25\text{ }^\circ\text{C}$ , $IF = 100\text{ MHz}$ , $LO = +15\text{ dBm}$ \*

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF/LO	3 - 7			3 - 4			GHz
Frequency Range, IF	DC - 3.5			DC - 3.5			GHz
Conversion Loss (As IRM)		7.5	9		8	9	dB
Image Rejection	20	27		28	32		dB
1 dB Compression (Input)		12			12		dBm
LO to RF Isolation	38	43		38	40		dB
LO to IF Isolation	26	30		32	33		dB
IP3 (Input)		22			17		dBm
Amplitude Balance		0.1			0.3		dB
Phase Balance		3			3		Deg

\* Unless otherwise noted, all measurements performed as downconverter.

# HMC620\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

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## COMPARABLE PARTS

View a parametric search of comparable parts.

## EVALUATION KITS

- HMC620LC4 Evaluation Board

## DOCUMENTATION

### Data Sheet

- HMC620 Die Data Sheet
- HMC620LC4: GaAs MMIC I/Q Mixer 3-7 GHz Data Sheet

## TOOLS AND SIMULATIONS

- HMC620 S-Parameters

## REFERENCE MATERIALS

### Quality Documentation

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: MESFET-B (QTR: 2013-00245)

## DESIGN RESOURCES

- HMC620 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC620 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

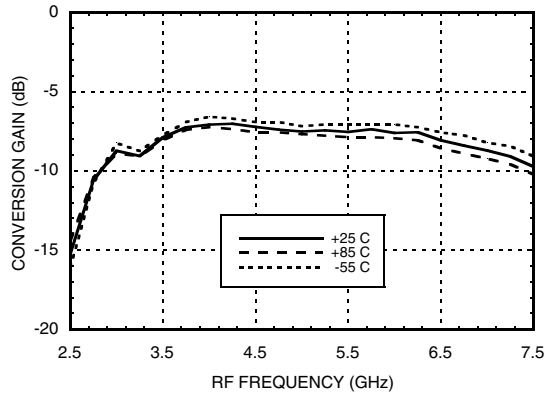
Submit feedback for this data sheet.



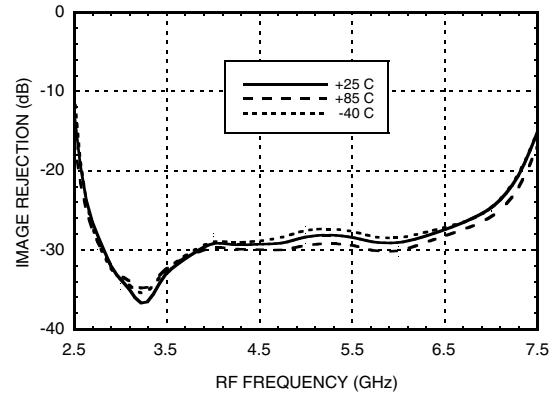
**GaAs MMIC I/Q MIXER  
3 - 7 GHz**

Data taken As IRM With External IF 90° Hybrid

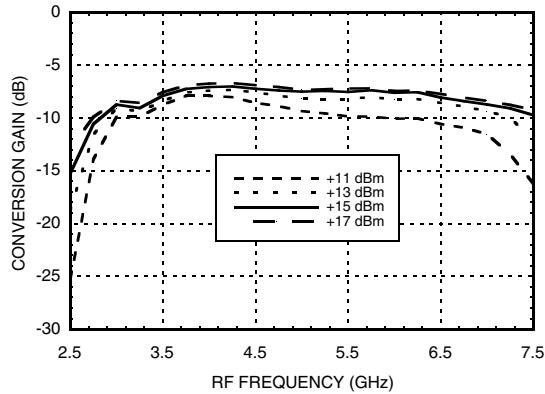
**Conversion Gain vs. Temperature**



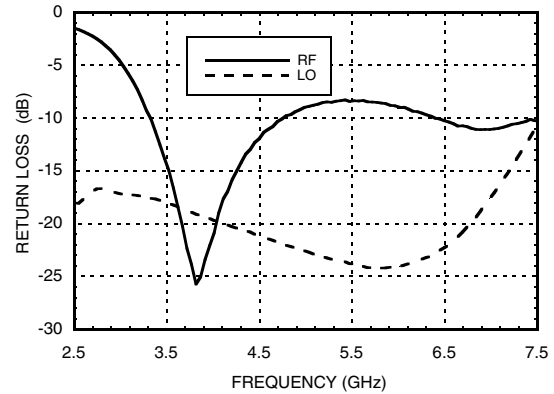
**Image Rejection vs. Temperature**



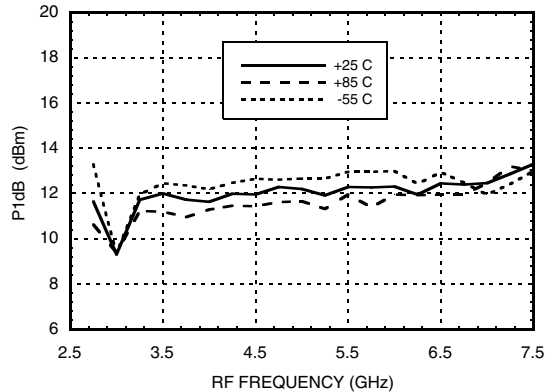
**Conversion Gain vs. LO Drive**



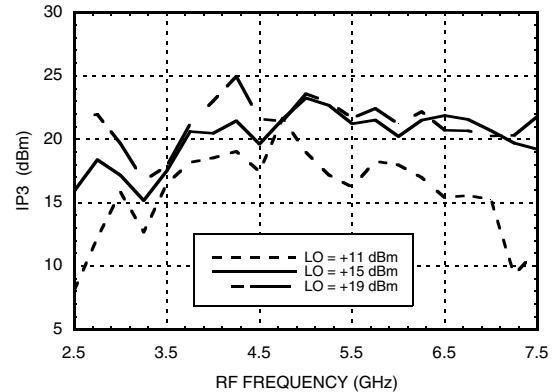
**Return Loss**



**Input P1dB vs. Temperature**



**Input IP3 vs. LO Drive**



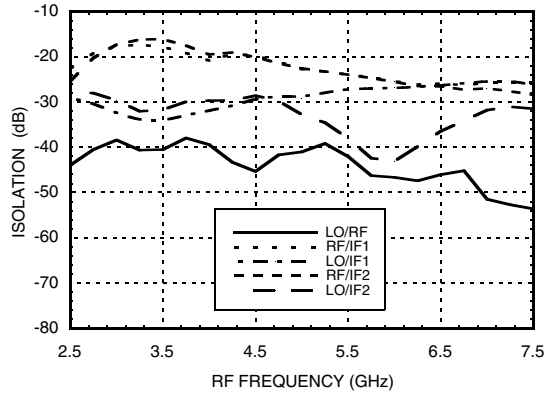
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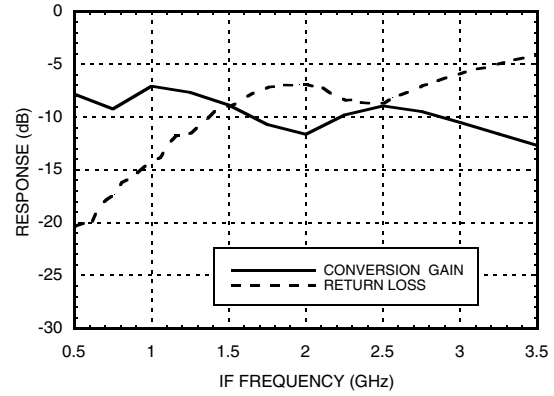


**GaAs MMIC I/Q MIXER  
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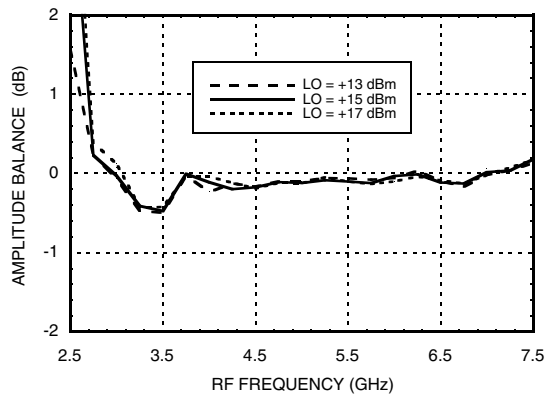
**Isolations**



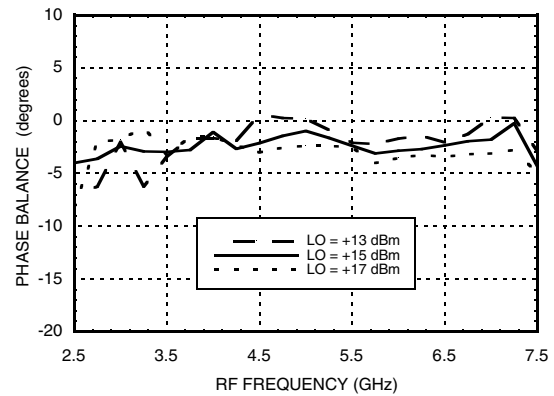
**IF Bandwidth\***



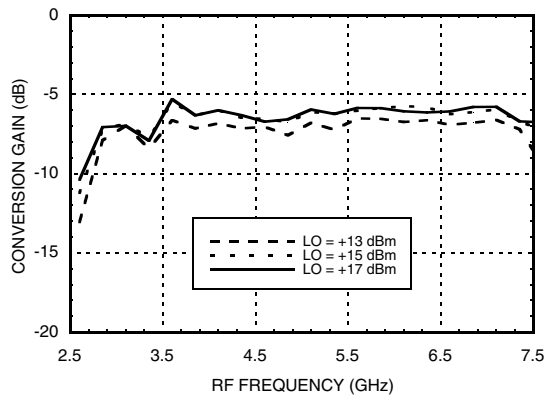
**Amplitude Balance vs. LO Drive**



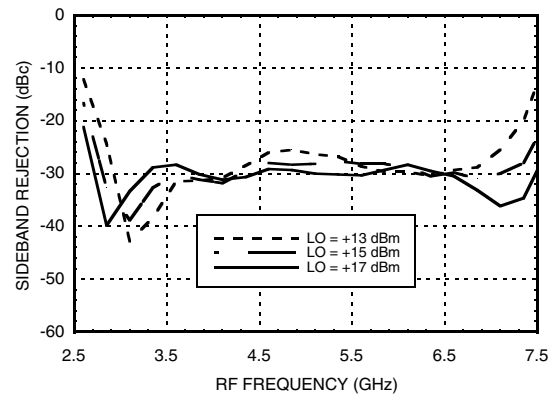
**Phase Balance vs. LO Drive**



**Upconverter Performance Conversion Gain vs. LO Drive**



**Upconverter Performance Sideband Rejection vs. LO Drive**



\* Conversion gain data taken with external IF 90° hybrid

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**GaAs MMIC I/Q MIXER  
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**Harmonics of LO**

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
2.5	29	35	48	30
3	26	33	51	39
4	28	32	39	43
5	28	36	45	52
6	36	44	60	41
7	40	36	58	34
7	46	37	55	46

LO = +15 dBm  
Values in dBc below input LO level measured at RF Port.

**MxN Spurious Outputs**

mRF	nLO				
	0	1	2	3	4
0	xx	1	15	28	69
1	15	0	30	39	50
2	69	61	78	60	71
3	95	95	95	73	95
4	95	95	95	95	95

RF = 5.6 GHz @ -10 dBm  
LO = 5.5 GHz @ +15 dBm  
Data taken without IF 90° hybrid  
All values in dBc with reference to output power at IF = 100 MHz

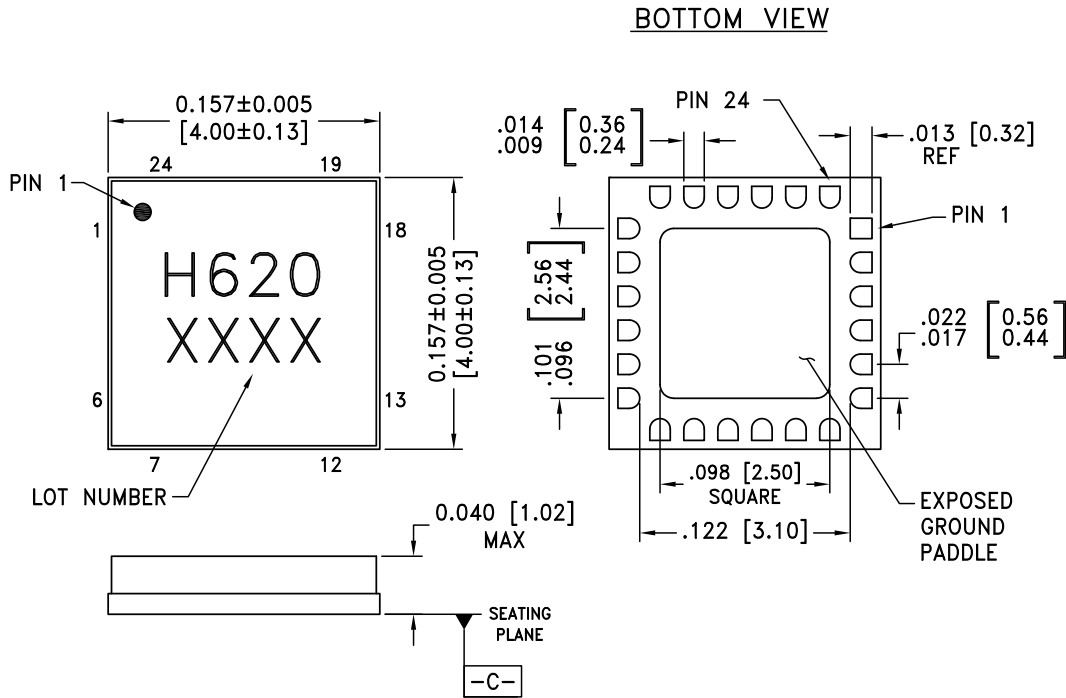
**Absolute Maximum Ratings**

RF / IF Input	+20 dBm
LO Drive	+27 dBm
Channel Temperature	150 °C
Continuous Pdiss (T=85°C) (derate 8.93 mW/°C above 85°C)	579 mW
Thermal Resistance (R <sub>TH</sub> ) (channel to die bottom)	112 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

### Outline Drawing



**NOTES:**

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30 - 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

### Package Information


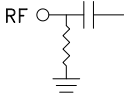
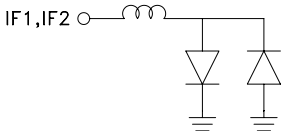
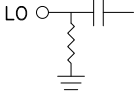
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC620LC4	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H620 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

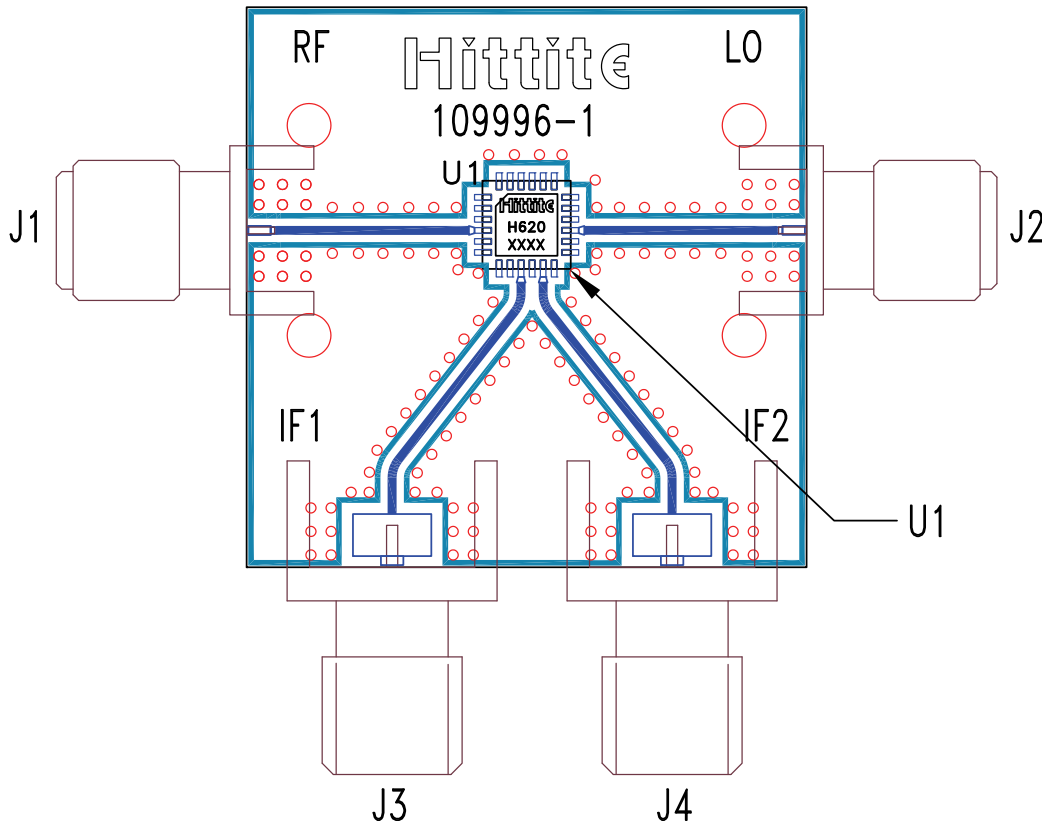


### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 6 - 8, 10, 13, 17 - 24	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
3, 5, 12, 14, 16	GND	These pins and package bottom must be connected to RF/DC ground.	
4	RF	This pin is DC coupled and matched to 50 Ohms.	
9	IF1	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 3mA of current or part non-function and possible part failure will result.	
11	IF2		
15	LO	This pin is DC coupled and matched to 50 Ohms.	



**Evaluation PCB**



**List of Materials for Evaluation PCB 109998 [1]**

Item	Description
J1, J2	PCB Mount SMA RF Connector, SRI
J3 - J4	PCB Mount SMA Connector, Johnson
U1	HMC620LC4
PCB [2]	109996 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



